

	Typ	L #	Hits	S arch T xt	DBs	Time Stamp
1	BRS	L1	8485	gate near4 (second! or another or differ\$4) near4 (resistiv\$4 or ohmic or conductiv\$4)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 17:45
2	BRS	L2	886	1 same (concentration or dos\$4)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 15:44
3	BRS	L3	8485	gate near4 (second! or another or differ\$4) near4 (resistiv\$4 or ohmic or conductiv\$4)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:14
4	BRS	L4	886	3 same (concentration or dos\$4)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:15
5	BRS	L5	256	4 same (inplant\$8 or implant\$8)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:15

	Typ	L #	Hits	S arch Text	DBs	Tim Stamp
6	BRS	L6	162763	cmos or "complementary metal oxide semiconductor" or mosfet or "metal oxide semiconductor field effect transistor"	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:16
7	BRS	L7	803	(second! or another or differ\$4) near2 (inplant or inplanting or implanted or implant or implanted or implanting) near4 gate	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:17
8	BRS	L8	142148	(4T or memory) adj (cell or sram or dram or (random adj access adj3 memory))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:17
9	BRS	L9	175	7 and 8	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:31
10	IS&R	L11	47	(438/176).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 16:31

	Typ	L #	Hits	S arch T xt	DBs	Tim Stamp
11	IS&R	L24	1277	(438/217) .CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 17:45
12	IS&R	L26	431	(257/204) .CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 17:50
13	IS&R	L27	589	(257/371) .CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 18:05
14	IS&R	L28	1059	(257/288) .CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 18:27
15	IS&R	L29	760	(257/341) .CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 18:32

	Typ	L #	Hits	Search T xt	DBs	Tim Stamp
16	IS&R	L30	98	(438/181).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 18:38
17	IS&R	L31	100	(438/184).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 18:58
18	IS&R	L32	274	(438/276).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 19:08
19	IS&R	L33	485	(438/231).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/04/29 19:20